

Pb Free Plating Product

## MUR880G



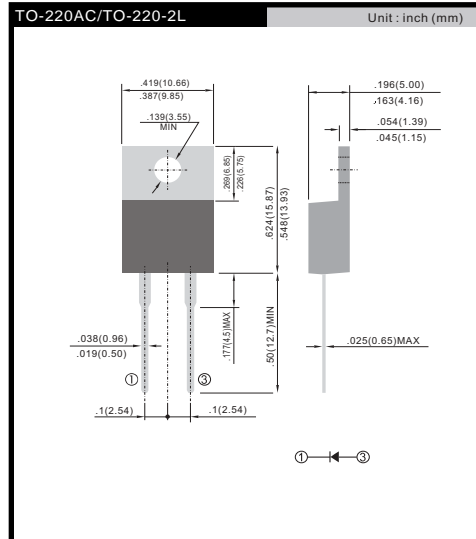
8.0 Amperes, 800 Volts Heat Sink Package Ultra Fast Recovery Rectifiers

### Features

- ◆ Epitaxial wafer with good soft recovery characteristics
- ◆ Fast recovery time for high efficiency
- ◆ Low reverse leakage current
- ◆ High surge capacity

### Mechanical Data

- ◆ Case: Heatsink TO-220AC/TO-220-2P
- ◆ Terminals: Lead solderable per MIL-STD-202, Method 208
- ◆ Polarity: As marked
- ◆ Standard packaging: Any
- ◆ Weight: 0.08 ounces, 1.9 gram approximately



### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	MUR880G	UNIT
Marking code on the device body		MUR880G	
Repetitive peak reverse voltage	$V_{RRM}$	800	V
Reverse voltage, total rms value	$V_{R(RMS)}$	560	V
Forward current	$I_{F(AV)}$	8	A
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	100	A
Junction temperature	$T_J$	-55 to +175	$^\circ\text{C}$
Storage temperature	$T_{STG}$	-55 to +175	$^\circ\text{C}$

<b>THERMAL PERFORMANCE</b>			
<b>PARAMETER</b>	<b>SYMBOL</b>	<b>LIMIT</b>	<b>UNIT</b>
Junction-to-lead thermal resistance	$R_{\theta JL}$	3.5	°C/W
Junction-to-ambient thermal resistance	$R_{\theta JA}$	6.5	°C/W
Junction-to-case thermal resistance	$R_{\theta JC}$	4	°C/W

**Thermal Performance Note:** Mounted on Heat sink Size of 4"x6"x0.25" Al-Plate

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^\circ\text{C}$ unless otherwise noted)					
<b>PARAMETER</b>	<b>CONDITIONS</b>	<b>SYMBOL</b>	<b>TYP</b>	<b>MAX</b>	<b>UNIT</b>
Forward voltage per diode <sup>(1)</sup>	$I_F = 4\text{A}, T_J = 25^\circ\text{C}$	$V_F$	1.69	1.85	V
	$I_F = 8\text{A}, T_J = 25^\circ\text{C}$		2.00	2.30	V
	$I_F = 4\text{A}, T_J = 150^\circ\text{C}$		1.08	1.30	V
	$I_F = 8\text{A}, T_J = 150^\circ\text{C}$		1.34	1.65	V
Reverse current @ rated $V_R$ per diode <sup>(2)</sup>	$T_J = 25^\circ\text{C}$	$I_R$	-	1	$\mu\text{A}$
	$T_J = 150^\circ\text{C}$		-	200	$\mu\text{A}$
Junction capacitance	1 MHz, $V_R = 4.0\text{V}$	$C_J$	57	-	pF
Reverse recovery time	$I_F = 0.5\text{A}, I_R = 1.0\text{A}$ $I_{RR} = 0.25\text{A}$	$t_{rr}$	-	25	ns

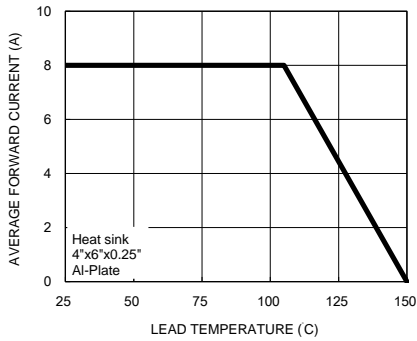
**Notes:**

1. Pulse test with  $PW = 0.3\text{ ms}$
2. Pulse test with  $PW = 30\text{ ms}$

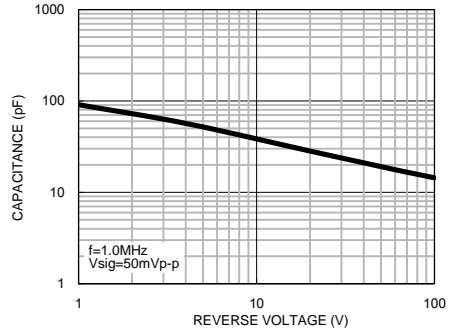
## CHARACTERISTICS CURVES

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

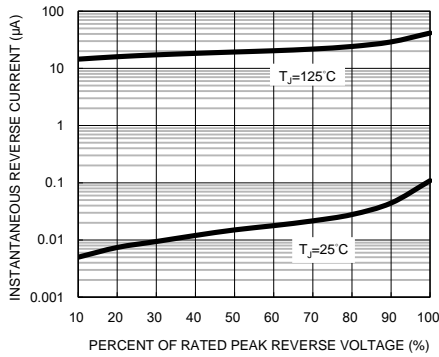
**Fig.1 Forward Current Derating Curve**



**Fig.2 Typical Junction Capacitance**



**Fig.3 Typical Reverse Characteristics**



**Fig.4 Typical Forward Characteristics**

